

SILICON BRIDGE RECTIFIERS

Features

- ◆ Rating to 1000V PRV
- ◆ Ideal for printed circuit board
- ◆ Reliable low cost construction utilizing molded plastic
- ◆ technique Plastic material has U/L lammability classification 94V-0
- ◆ Low forward voltage drop,high current capability

Mechanical Data

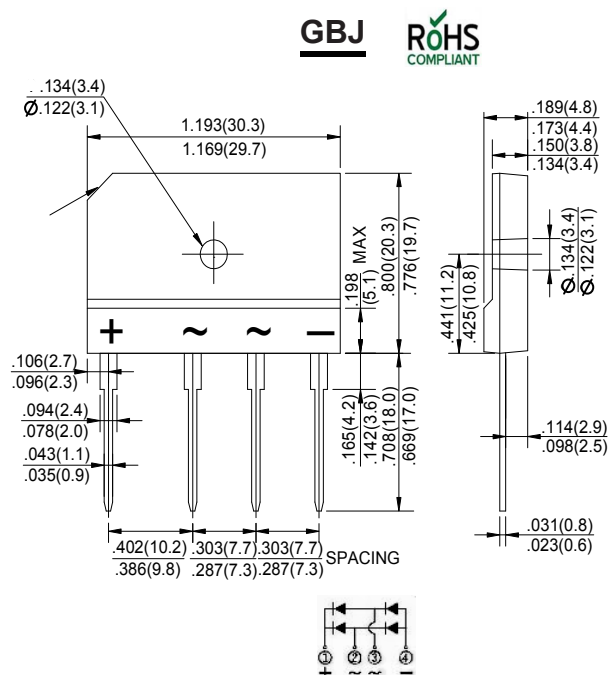
Case : JEDEC GBJ Molded plastic body

Terminals : Solder plated, solderable per MIL-STD-750,Method 2026

Polarity : Polarity symbol marking on body

Mounting Position : Any

Mounting Torque: 5in-lbs



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	MDD GBJ8005	MDD GBJ801	MDD GBJ802	MDD GBJ804	MDD GBJ806	MDD GBJ808	MDD GBJ810	UNITS
Marking Code									
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward (with heatsink NOTE 2) Rectified current @ $T_c=100^\circ\text{C}$ (without heatsink)	$I_{(AV)}$	8.0 3.4							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	200							A
Rating for Fusing ($t < 8.3\text{ms}$)	I^2t	166.0							A^2s
Maximum forward voltage at 4.0A DC	V_F	1.0							V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	I_R	10 0.5							μA mA
Typical Junction Capacitance (Note 1)	C_J	55							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	1.8							$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J	-55 to +150							$^\circ\text{C}$
storage temperature range	T_{STG}	-55 to +150							$^\circ\text{C}$

- NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Device mounted on 75mm*75mm*1.6mm cu plate heatsink.
3. The typical data above is for reference only.

Ratings And Characteristic Curves

FIG.1-FORWARD CURRENT DERATING CURVE

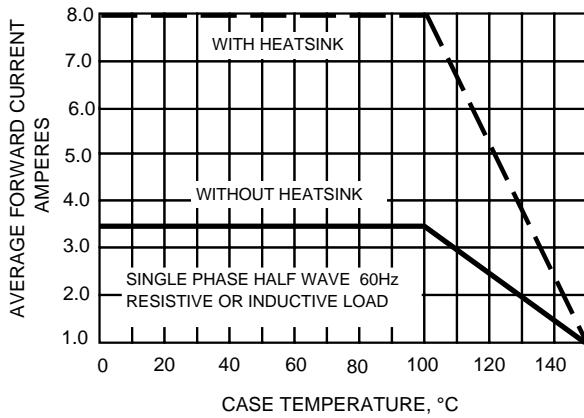


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

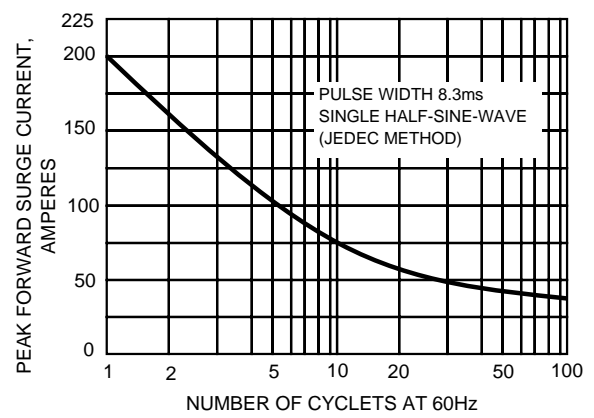


FIG.3-TYPICAL JUNCTION CAPACITANCE

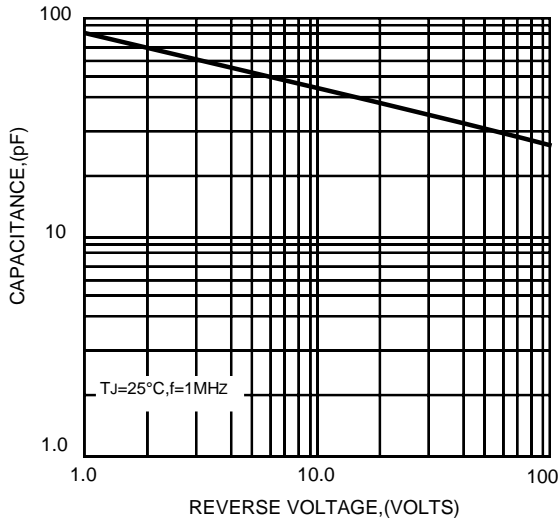


FIG.4-TYPICAL FORWARD CHARACTERISTICS

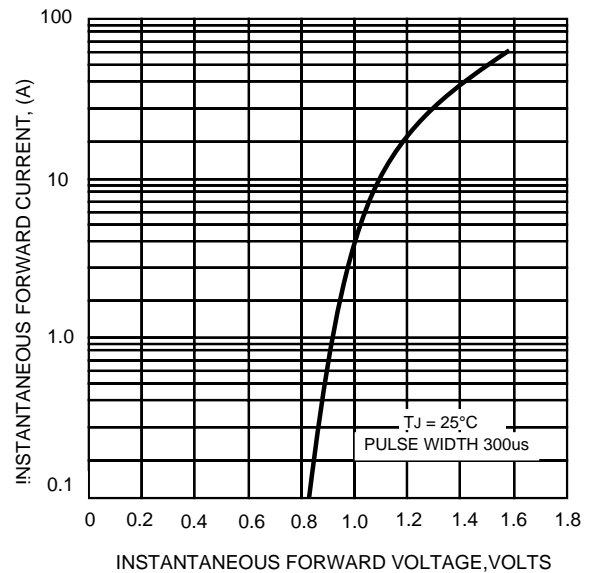
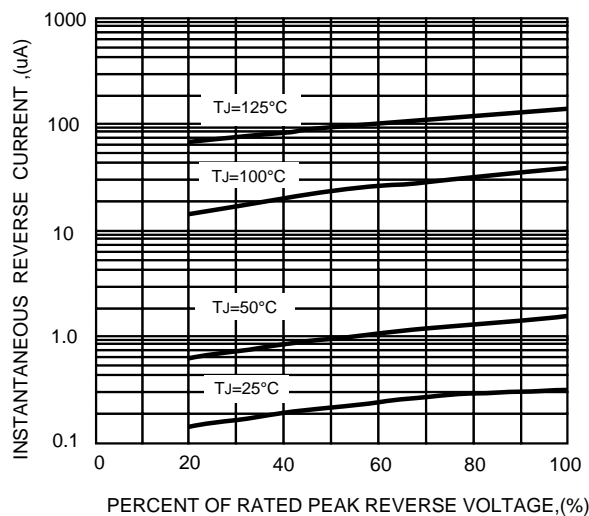


FIG.5-TYPICAL REVERSE CHARACTERISTICS



The curve above is for reference only.



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